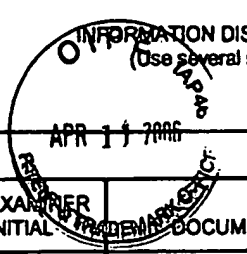


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| INFORMATION DISCLOSURE STATEMENT (Use several sheets if necessary)  | | | | APPLICANT Robert L. Thornton | | | | |
| | | | | FILING DATE 8/20/2001 | | GROUP ART UNIT 2828 | | |
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











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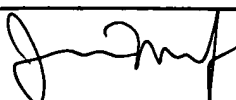
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